



Bipolar NPN Bare Die – BTN6020

Part Description

The BTN6020 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

Key Parameters:

- VCBO = 15V
- VCEO = 15V
- VEBO = 5V
- hFE = 250- @ VCE = 2V, IC = 0.5A
- VCE(Sat) = 0.3V @ IC = 3A, IB = 60mA
- fT = 250 MHz @ VCE = 2V, IE = 0A
- COBO = 33pF @ VCB = 10V

Features

Very Low VCE(sat). Designed to provide performance equivalent to SANYO 2SC5564

Die Size (Unawn)

920µm X 920µm, 36 Mils X 36 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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